捷多邦,专业PCB打样工厂,24小时加**担近812,TL5812I** VACUUM FLUORESCENT DISPLAY DRIVERS

SLDS011B - OCTOBER 1985 - REVISED MAY 1993

- Drives up to 20 Lines
- 70-V Output Voltage Swing Capability
- 40-mA Output Source Current Capability
- High-Speed Serially-Shifted Data Input
- CMOS-Compatible Inputs
- Direct Replacement for Sprague UCN5812A

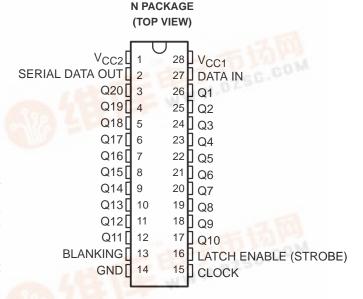
description

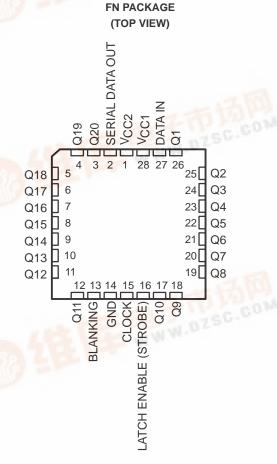
The TL5812 and TL5812I are monolithic BIDFET[†] integrated circuits designed to drive a dot matrix or segmented vacuum fluorescent display (VFD). Each device features a serial data output to cascade additional devices for large display arrays.

A 20-bit data word is serially loaded into the shift register on the low-to-high transition of CLOCK. Parallel data is transferred to the output buffers through a 20-bit D-type latch while LATCH ENABLE is high and is latched when LATCH ENABLE is low. When BLANKING is high, all outputs are low.

The outputs are totem-pole structures formed by npn emitter-follower and double-diffused MOS (DMOS) transistors with output voltage ratings of 70 V and a source-current capability of 40 mA. All inputs are CMOS compatible.

The TL5812 is characterized for operation from 0°C to 70°C. The TL5812I is characterized for operation from -40°C to 85°C.



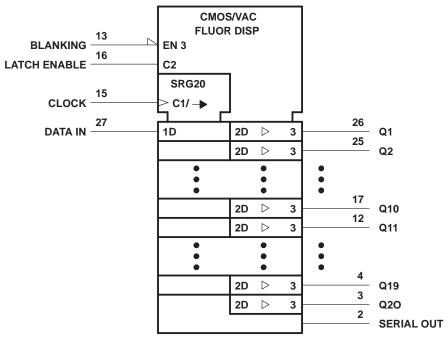




BIDEET – Bipolar, double-diffused, N-channel and P-channel MOS transistors on same chip. This is a patented process.

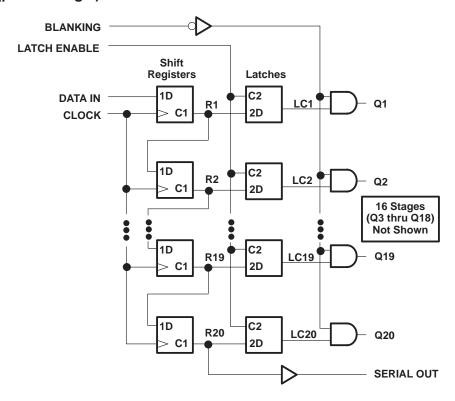


logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





TL5812, TL5812I VACUUM FLUORESCENT DISPLAY DRIVERS

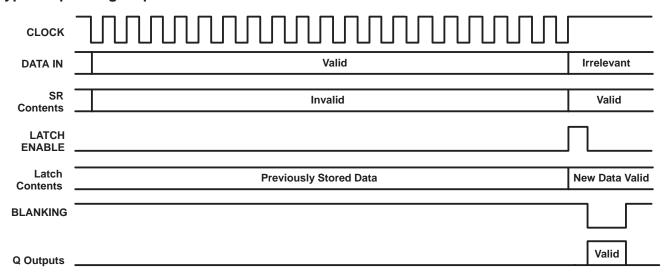
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FUNCTION TABLE

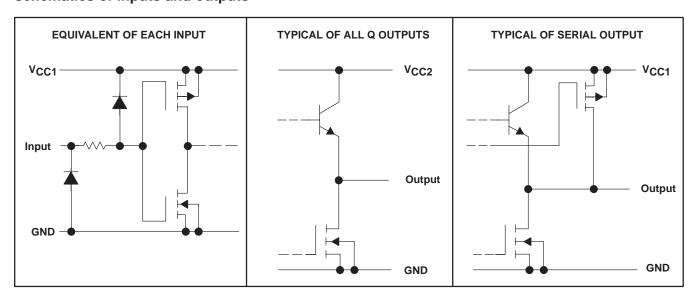
FUNCTION	CONTROL INPUTS		SHIFT REGISTERS	LATCHES	OUTPUTS			
	СГОСК	LATCH ENABLE	BLANKING	R1 THRU R20	LC1 THRU LC20	SERIAL	Q1 THRU Q20	
Load	↑ No↑	X X	X X	Load and shift [†] No change	Determined by LATCH ENABLE‡	R20 R20	Determined by BLANKING	
Latch	X X	L H	X X	As determined above	Stored data New data	R20 R20	Determined by BLANKING	
Blank	X X	X X	H L	As determined above	Determined by LATCH ENABLE‡	R20 R20	All L LC1 thru LC10, respectively	

H = high level, L = low level, X = irrelevant, $\uparrow = low-to-high-level transition$.

typical operating sequence



schematics of inputs and outputs





[†] R20 takes on the state of R19, R19 takes on the state of R18, ... R2 takes on the state of R1, and R1 takes on the state of the data input.

[‡] New data enter the latches while LATCH ENABLE is high. These data are stored while LATCH ENABLE is low.

TL5812, TL5812I VACUUM FLUORESCENT DISPLAY DRIVERS

SLDS011B - OCTOBER 1985 - REVISED MAY 1993

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V _{CC1} (see Note 1)	
Supply voltage, V _{CC2}	
Output voltage, VO	
Input voltage range, V _I	0.3 V to V _{CC1} +0.3 V
Output current, I _O	–40 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range: TL5812	0°C to 70°C
TL5812I	–40°C to 85°C
Storage temperature range,	–65°C to 150°C
Case temperature for 10 seconds: FN package	260°C
Lead temperature 1.6 mm (1/16 inch) from case for 10 seconds: N package	260°C

NOTE 1: All voltage values are with respect to GND.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING		
FN	1400 mW	11.2 mW/°C	896 mW	728 mW		
N	1150 mW	9.2 mW/°C	736 mW	598 mW		

recommended operating conditions

		MIN	NOM MAX	UNIT			
Supply voltage, V _{CC1}		4.5	15	V			
Supply voltage, V _{CC2}	Supply voltage, V _{CC2} 0 60						
High-level input voltage, VIH	V _{CC1} -1.5	V _{CC1} +0.3	V				
Low-level input voltage, V _{IL}			0.8	V			
High-level output current, IOH			-40	mV			
On creating free pir temperature T	TL5812	0	70	°C			
Operating free-air temperature, T _A	TL5812I	-40	85				

[†] The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for logic voltage levels.



TL5812, TL5812I VACUUM FLUORESCENT DISPLAY DRIVERS

SLDS011B - OCTOBER 1985 - REVISED MAY 1993

electrical characteristics over operating free-air temperature range, V_{DD} = 5 V to 15 V, V_{BB} = 60 V (unless otherwise noted)

PARAMETER			TEST	MIN	TYP [‡]	MAX	UNIT	
	High-level output	Q outputs	$I_{OH} = -25 \text{ mA}$		57.5	58.2		
VOH		SERIAL DATA OUT	$V_{CC1} = 5 \text{ V},$	$I_{OH} = -20 \mu A$	4.5	4.9		V
		SERIAL DATA OUT	$V_{CC1} = 15 \text{ V},$	$I_{OH} = -20 \mu A$	14.5	14.9		
	Low-level output voltage	Q outputs	$I_{OL} = 1 \text{ mA},$	BLANKING at V _{CC1}		0.7	1.5	
VOL		SERIAL DATA OUT	V _{CC1} = 5 V,	I _{OL} = 20 μA		0.06	0.3	V
			$V_{CC1} = 15 \text{ V},$	I _{OL} = 20 μA		0.03	0.3	
lіН	High-level input current		$V_I = V_{CC1}$			0.3	1	μΑ
IJL	Low-level input current		V _I = 0			-0.3	-1	μΑ
loL	Low-level output current (pulldown current)		$V_0 = 60 \text{ V},$	BLANKING at V _{CC1}	2.5	3.2		μΑ
I _{O(off)}	Off-state output current		$V_{O} = 0$,	BLANKING at V _{CC1}		< - 1	-15	μΑ
loos	Committee command frame Man		Outputs high				8	mA
ICC2	Supply current from V _{CC2}		Outputs low			0.02	0.5	IIIA
laa.	Cumply ourrant from Voc	_	V _{CC1} = 5 V		1.5		3	m ^
ICC1	Supply current from V _{CC1}		V _{CC1} = 15 V			1.7	4	mA

 $[\]ddagger$ All typical characteristics are at T_A= 25°C.

timing requirements over operating free-air temperature range

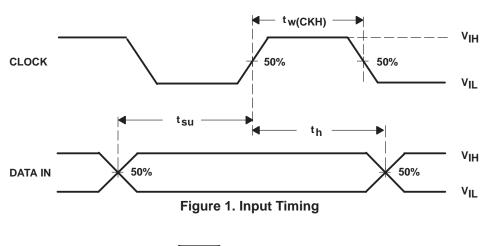
			MIN	MAX	UNIT
t _w (CKH)	Pulse duration, CLOCK high	V _{CC1} = 5 V	500		no
		V _{CC1} = 15 V	100		ns
^t w(LEH)	Pulse duration, LATCH ENABLE high	V _{CC1} = 5 V	500		ns
		V _{CC1} = 15 V	100		115
t _{su(D)}	Setup time, DATA IN before CLOCK↑	V _{CC1} = 5 V	150		ns
		V _{CC1} = 15 V	75		115
th(D)	Hold time, DATA IN after CLOCK↑	V _{CC1} = 5 V	150		
		V _{CC1} = 15 V	75		ns
^t d(CKH-LEH)	Delay time, CLOCK↑ to LATCH ENABLE high	V _{CC1} = 5 V	150		no
		V _{CC1} = 15 V	75		ns

switching characteristics, V_{BB} = 60 V, T_A = 25°C

PARAMETER				TYP	MAX	UNIT
t _{pd}	Propagation delay time, LATCH ENABLE to Q outputs	V _{CC1} = 5 V		2.2		
		V _{CC1} = 15 V		0.8		μs



PARAMETER MEASUREMENT INFORMATION



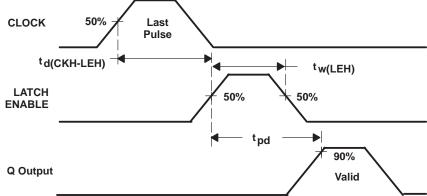


Figure 2. Output Switching Times

TEXAS

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THERMAL INFORMATION

DUTY CYCLE

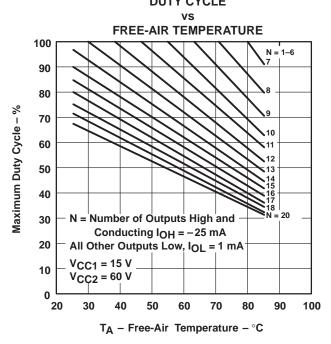


Figure 3

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